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<ul> <li>Operate With 3-V to 5.5-V V<sub>CC</sub> Supply</li> <li>Operate Up To 1 Mbit/s</li> </ul>	DB, DW, OR F (TOP	PW PACKAGE VIEW)
• Low Standby Current 1 μA Typ		20 FORCEOFF
• External Capacitors 4 $\times$ 0.1 $\mu$ F	C1+[]2	19 V <sub>CC</sub>
<ul> <li>Accept 5-V Logic Input With 3.3-V Supply</li> </ul>	V+[]3	18 GND
Latch-Up Performance Exceeds 100 mA Per	C1-[] 4	17 DOUT1
JESD 78, Class II	C2+[]5	16 RIN1
<ul> <li>RS-232 Bus-Pin ESD Protection Exceeds</li> </ul>	C2-[]6	15 ROUT1
	V-[] 7	14 🛛 FORCEON
±15 kV Using Human-Body Model (HBM)	DOUT2 🛛 8	13 DIN1
Applications	RIN2	12 DIN2
<ul> <li>Battery-Powered Systems, PDAs,</li> </ul>		11 INVALID
Notebooks, Laptops, Palmtop PCs, and	······································	

#### description/ordering information

**Hand-Held Equipment** 

The SN65C3223 and SN75C3223 consist of two line drivers, two line receivers, and a dual charge-pump circuit with  $\pm$ 15-kV ESD protection pin to pin (serial-port connection pins, including GND). The devices provide the electrical interface between an asynchronous communication controller and the serial-port connector. The charge pump and four small external capacitors allow operation from a single 3-V to 5.5-V supply. The devices operate at data signaling rates up to 1 Mbit/s and a driver output slew rate of 24 V/µs to 150 V/µs

Flexible control options for power management are available when the serial port is inactive. The auto-powerdown feature functions when FORCEON is low and FORCEOFF is high. During this mode of operation, if the device does not sense a valid RS-232 signal, the driver outputs are disabled. If FORCEOFF is set low and EN is high, both drivers and receivers are shut off, and the supply current is reduced to 1  $\mu$ A. Disconnecting the serial port or turning off the peripheral drivers causes auto-powerdown to occur. Auto-powerdown can be disabled when FORCEON and FORCEOFF are high. With auto-powerdown enabled, the device is activated automatically when a valid signal is applied to any receiver input. The INVALID output is used to notify the user if an RS-232 signal is present at any receiver input. INVALID is high (valid data) if any receiver input voltage is greater than 2.7 V or less than –2.7 V or has been between –0.3 V and 0.3 V for less than 30  $\mu$ s. Refer to Figure 4 for receiver input levels.

TA	PACKA	GE†	ORDERABLE PART NUMBER	TOP-SIDE MARKING
		Tube of 25	SN75C3223DW	7500000
	SOIC – DW	Reel of 2000	SN75C3223DWR	75C3223
0°C to 70°C	SSOP – DB	Reel of 2000	SN75C3223DBR	CA3223
		Tube of 70	SN75C3223PW	
	TSSOP – PW	Reel of 2000	SN75C3223PWR	CA3223
	0010 014	Tube of 25	SN65C3223DW	
	SOIC – DW	Reel of 2000	SN65C3223DWR	65C3223
−40°C to 85°C	SSOP – DB	Reel of 2000	SN65C3223DBR	CB3223
	7000D DW	Tube of 70	SN65C3223PW	0.00000
	TSSOP – PW	Reel of 2000	SN65C3223PWR	CB3223

#### **ORDERING INFORMATION**

<sup>†</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



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**Function Tables** 

			EACH DRIVER		
		INPUTS		OUTPUT	
DIN	FORCEON	FORCEOFF	VALID RIN RS-232 LEVEL	DOUT	DRIVER STATUS
Х	Х	L	Х	Z	Powered off
L	Н	Н	Х	Н	Normal operation with
Н	Н	Н	Х	L	auto-powerdown disabled
L	L	Н	Yes	Н	Normal operation with
н	L	Н	Yes	L	auto-powerdown enabled
L	L	Н	No	Z	Powered off by
Н	L	Н	No	Z	auto-powerdown feature

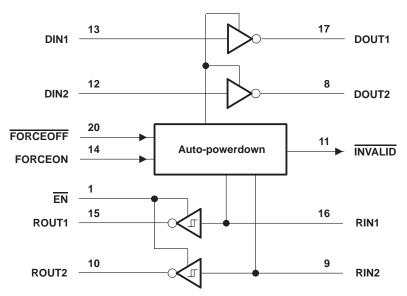
H = high level, L = low level, X = irrelevant, Z = high impedance

EACH RECEIVER

	INP	PUTS	OUTPUT
RIN	EN	VALID RIN RS-232 LEVEL	ROUT
L	L	Х	Н
н	L	Х	L
Х	Н	Х	Z
Open	L	No	Н

H = high level, L = low level, X = irrelevant, Z = high impedance (off), Open = input disconnected or connected driver off

logic diagram (positive logic)





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#### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>†</sup>

Supply voltage range, V <sub>CC</sub> (see Note 1) Positive output supply voltage range, V+ (see Note 1) Negative output supply voltage range, V– (see Note 1)	0.3 V to 7 V 0.3 V to -7 V
Supply voltage difference, V+ – V– (see Note 1)	
Input voltage range, VI: Driver, FORCEOFF, FORCEON, EN	$\dots \dots \dots \dots -0.3 \text{ V to 6 V}$
Receiver	–25 V to 25 V
Output voltage range, V <sub>O</sub> : Driver	13.2 V to 13.2 V
Receiver, INVALID	$\dots$ –0.3 V to V <sub>CC</sub> + 0.3 V
Package thermal impedance, $\theta_{JA}$ (see Notes 2 and 3): DB package	
	58°C/W
	83°C/W
Operating virtual junction temperature, T <sub>J</sub>	
Storage temperature range, T <sub>stg</sub>	

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltages are with respect to network GND.

- 2. Maximum power dissipation is a function of  $T_J(max)$ ,  $\theta_{JA}$ , and  $T_A$ . The maximum allowable power dissipation at any allowable ambient temperature is  $P_D = (T_J(max) T_A)/\theta_{JA}$ . Operating at the absolute maximum  $T_J$  of 150°C can affect reliability.
- 3. The package thermal impedance is calculated in accordance with JESD 51-7.

#### recommended operating conditions (see Note 4 and Figure 6)

				MIN	NOM	MAX	UNIT
	cc Supply voltage		$V_{CC} = 3.3 V$	3	3.3	3.6	
Vcc			$V_{CC} = 5 V$	4.5	5	5.5	V
		r and control high-level input voltage $DIN, \overline{EN}, \overline{FORCEOFF}, \overline{VCC} = 3.3 V$ FORCEON $V_{CC} = 5 V$	$V_{CC} = 3.3 V$	2			V
VIH	Driver and control high-level input voltage		$V_{CC} = 5 V$	2.4			V
VIL	Driver and control low-level input voltage	DIN, EN, FORCEOFF, FORCEO	NC			0.8	V
	Driver and control input voltage	DIN, EN, FORCEOFF, FORCEO	NC	0		5.5	N/
VI	Receiver input voltage			-25		25	V
т.			SN65C3223	-40		85	°C
Τ <sub>Α</sub>	Operating free-air temperature		SN65C3223	0		70	U

NOTE 4: Test conditions are C1–C4 = 0.1  $\mu$ F at V<sub>CC</sub> = 3.3 V ± 0.3 V; C1 = 0.047  $\mu$ F, C2–C4 = 0.33  $\mu$ F at V<sub>CC</sub> = 5 V ± 0.5 V.

# electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 4 and Figure 6)

PARAMETER		TEST CONDITIONS	MIN	TYP‡	MAX	UNIT	
Ц	Input leakage current	EN, FORCEOFF, FORCEON			±0.01	±1	μΑ
		Auto-powerdown disabled	$\frac{\text{No load,}}{\text{FORCEOFF, FORCEON at V}_{\text{CC}}}$		0.3	1	mA
lcc	Supply current	Powered off	No load, FORCEOFF at GND		1	10	
		Auto-powerdown enabled	No load, FORCEOFF at V <sub>CC</sub> , FORCEON at GND, All RIN are open or grounded		1	10	μΑ

<sup>‡</sup> All typical values are at V<sub>CC</sub> = 3.3 V or V<sub>CC</sub> = 5 V, and T<sub>A</sub> = 25°C.

NOTE 4: Test conditions are C1–C4 = 0.1  $\mu$ F at V<sub>CC</sub> = 3.3 V ± 0.3 V; C1 = 0.047  $\mu$ F, C2–C4 = 0.33  $\mu$ F at V<sub>CC</sub> = 5 V ± 0.5 V.



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## **DRIVER SECTION**

#### electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 4 and Figure 6)

	PARAMETER	TE	ST CONDITION	S	MIN	TYP†	MAX	UNIT
VOH	High-level output voltage	DOUT at $R_L = 3 k\Omega$ to G	ND		5	5.4		V
VOL	Low-level output voltage	DOUT at $R_L = 3 k\Omega$ to G	DOUT at $R_L = 3 k\Omega$ to GND			-5.4		V
Iн	High-level input current	VI = VCC				±0.01	±1	μΑ
١ <sub>IL</sub>	Low-level input current	V <sub>I</sub> at GND				±0.01	±1	μΑ
		V <sub>CC</sub> = 3.6 V,	VO = 0 V			±35	±60	
los	Short-circuit output current‡	V <sub>CC</sub> = 5.5 V,	VO = 0 V			±35	±90	mA
r <sub>o</sub>	Output resistance	V <sub>CC</sub> , V+, and V– = 0 V,	$V_{O} = \pm 2 V$		300	10M		Ω
		FORCEOFF = GND	$V_{O} = \pm 12 V$ ,	$V_{CC}$ = 3 V to 3.6 V			±25	
loff	Output leakage current	FORGEOFF = GND	$V_{O} = \pm 10 V$ ,	$V_{CC}$ = 4.5 V to 5.5 V			±25	μΑ

<sup>†</sup> All typical values are at V<sub>CC</sub> = 3.3 V or V<sub>CC</sub> = 5 V, and T<sub>A</sub> = 25°C.

<sup>‡</sup> Short-circuit durations should be controlled to prevent exceeding the device absolute power-dissipation ratings, and not more than one output should be shorted at a time.

NOTE 4: Test conditions are C1–C4 = 0.1  $\mu$ F at V<sub>CC</sub> = 3.3 V ± 0.3 V; C1 = 0.047  $\mu$ F, C2–C4 = 0.33  $\mu$ F at V<sub>CC</sub> = 5 V ± 0.5 V.

#### switching characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 4 and Figure 6)

	PARAMETER		TEST CONDITIONS		MIN	TYP†	MAX	UNIT
	Maximum data rate $R_L = 3 k\Omega$ , (see Figure 1) One DOUT switching	C <sub>L</sub> = 1000 pF		250				
		C <sub>L</sub> = 250 pF,	$V_{CC}$ = 3 V to 4.5 V	1000			kbit/s	
	(000 1 iguro 1)	one beer entering	C <sub>L</sub> = 1000 pF,	$V_{CC}$ = 4.5 V to 5.5 V	1000			
tsk(p)	Pulse skew <sup>§</sup>	$C_{L} = 150 \text{ pF} \text{ to } 2500 \text{ pF},$	$R_L = 3 \ k\Omega$ to 7 $k\Omega$ ,	See Figure 2		300		ns
SR(tr)	Slew rate, transition region (see Figure 1)	V <sub>CC</sub> = 3.3 V, R <sub>L</sub> = 3 kΩ to 7 kΩ	C <sub>L</sub> = 150 pF to 1000	pF	18		150	V/µs

<sup>†</sup> All typical values are at V<sub>CC</sub> = 3.3 V or V<sub>CC</sub> = 5 V, and T<sub>A</sub> = 25°C.

\$ Pulse skew is defined as  $|tp_{LH} - tp_{HL}|$  of each channel of the same device. NOTE 4: Test conditions are C1-C4 = 0.1  $\mu$ F at V<sub>CC</sub> = 3.3 V ± 0.3 V; C1 = 0.047  $\mu$ F, C2-C4 = 0.33  $\mu$ F at V<sub>CC</sub> = 5 V ± 0.5 V.



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#### **RECEIVER SECTION**

# electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 4 and Figure 6)

	PARAMETER	TEST CONDITIONS	MIN	TYP†	MAX	UNIT
VOH	High-level output voltage	$I_{OH} = -1 \text{ mA}$	V <sub>CC</sub> – 0.6	V <sub>CC</sub> – 0.1		V
VOL	Low-level output voltage	I <sub>OL</sub> = 1.6 mA			0.4	V
N/	Desitive spin picture three held welters	V <sub>CC</sub> = 3.3 V		1.6	2.4	
VIT+	Positive-going input threshold voltage	$V_{CC} = 5 V$		1.9	2.4	V
	No. 2010 and the stand thread add and the set	V <sub>CC</sub> = 3.3 V	0.6	1.1		
VIT-	Negative-going input threshold voltage	$V_{CC} = 5 V$	0.8	1.4		V
V <sub>hys</sub>	Input hysteresis (V <sub>IT+</sub> – V <sub>IT</sub> –)			0.5		V
loff	Output leakage current	$\overline{EN} = V_{CC}$		±0.05	±10	μΑ
r <sub>i</sub>	Input resistance	$V_I = \pm 3 V \text{ to } \pm 25 V$	3	5	7	kΩ

<sup>†</sup> All typical values are at V<sub>CC</sub> = 3.3 V or V<sub>CC</sub> = 5 V, and T<sub>A</sub> = 25°C.

NOTE 4: Test conditions are C1–C4 = 0.1  $\mu$ F at V<sub>CC</sub> = 3.3 V ± 0.3 V; C1 = 0.047  $\mu$ F, C2–C4 = 0.33  $\mu$ F at V<sub>CC</sub> = 5 V ± 0.5 V.

# switching characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 4)

PARAMETER		TEST (	TEST CONDITIONS		MAX	UNIT
<sup>t</sup> PLH	Propagation delay time, low- to high-level output	CL= 150 pF,	See Figure 3	150		ns
<sup>t</sup> PHL	Propagation delay time, high- to low-level output	C <sub>L</sub> = 150 pF,	See Figure 3	150		ns
t <sub>en</sub>	Output enable time	C <sub>L</sub> = 150 pF, See Figure 4	$R_L = 3 k\Omega$ ,	200		ns
<sup>t</sup> dis	Output disable time	C <sub>L</sub> = 150 pF, See Figure 4	RL = 3 kΩ,	200		ns
<sup>t</sup> sk(p)	Pulse skew <sup>‡</sup>	See Figure 3		50		ns

<sup>†</sup> All typical values are at  $V_{CC}$  = 3.3 V or  $V_{CC}$  = 5 V, and  $T_A$  = 25°C.

<sup>‡</sup>Pulse skew is defined as |t<sub>PLH</sub> – t<sub>PHL</sub>| of each channel of the same device.

NOTE 4: Test conditions are C1–C4 = 0.1  $\mu$ F at V<sub>CC</sub> = 3.3 V ± 0.3 V; C1 = 0.047  $\mu$ F, C2–C4 = 0.33  $\mu$ F at V<sub>CC</sub> = 5 V ± 0.5 V.



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## **AUTO-POWERDOWN SECTION**

# electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 5)

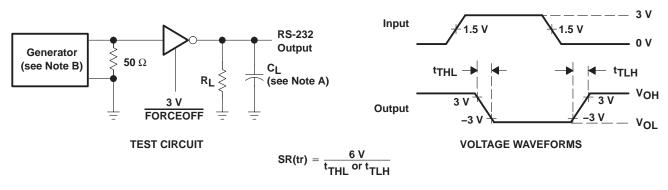
	PARAMETER	TEST C	ONDITIONS	MIN	MAX	UNIT
V <sub>T+(valid)</sub>	Receiver input threshold for INVALID high-level output voltage	FORCEON = GND,	$\overline{FORCEOFF} = V_{CC}$		2.7	V
V <sub>T-(valid)</sub>	Receiver input threshold for INVALID high-level output voltage	FORCEON = GND,	$\overline{FORCEOFF} = V_{CC}$	-2.7		V
V <sub>T(invalid)</sub>	Receiver input threshold for INVALID low-level output voltage	FORCEON = GND,	$\overline{FORCEOFF} = V_{CC}$	-0.3	0.3	V
VOH	INVALID high-level output voltage	$\frac{I_{OH} = -1 \text{ mA}}{FORCEOFF} = V_{CC}$	FORCEON = GND,	V <sub>CC</sub> – 0.6		V
VOL	INVALID low-level output voltage	$\frac{I_{OL} = 1.6 \text{ mA}}{FORCEOFF} = V_{CC}$	FORCEON = GND,		0.4	V

# switching characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 5)

	PARAMETER	TYP†	UNIT
<sup>t</sup> valid	Propagation delay time, low- to high-level output	1	μs
<sup>t</sup> invalid	Propagation delay time, high- to low-level output	30	μs
t <sub>en</sub>	Supply enable time	100	μs

<sup>†</sup> All typical values are at  $V_{CC}$  = 3.3 V or  $V_{CC}$  = 5 V, and  $T_A$  = 25°C.

## PARAMETER MEASUREMENT INFORMATION



NOTES: A. CL includes probe and jig capacitance.

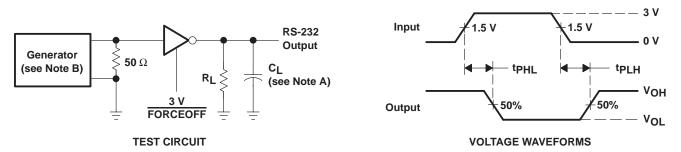
B. The pulse generator has the following characteristics: PRR = 250 kbit/s,  $Z_0 = 50 \Omega$ , 50% duty cycle,  $t_f \le 10$  ns.  $t_f \le 10$  ns.

#### Figure 1. Driver Slew Rate



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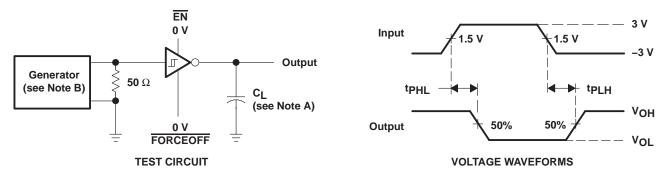
### PARAMETER MEASUREMENT INFORMATION



NOTES: A. CL includes probe and jig capacitance.

B. The pulse generator has the following characteristics: PRR = 250 kbit/s,  $Z_O = 50 \Omega$ , 50% duty cycle,  $t_r \le 10$  ns,  $t_f \le 10$  ns.

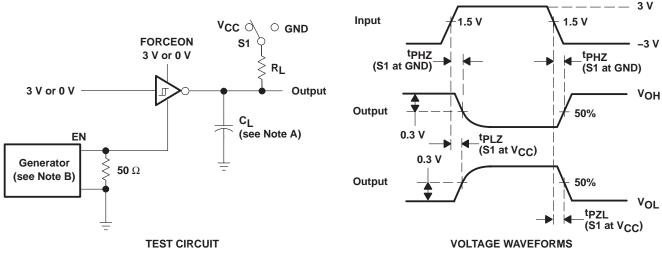
#### Figure 2. Driver Pulse Skew



NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

B. The pulse generator has the following characteristics:  $Z_O = 50 \Omega$ , 50% duty cycle,  $t_f \le 10 \text{ ns}$ .  $t_f \le 10 \text{ ns}$ .

**Figure 3. Receiver Propagation Delay Times** 



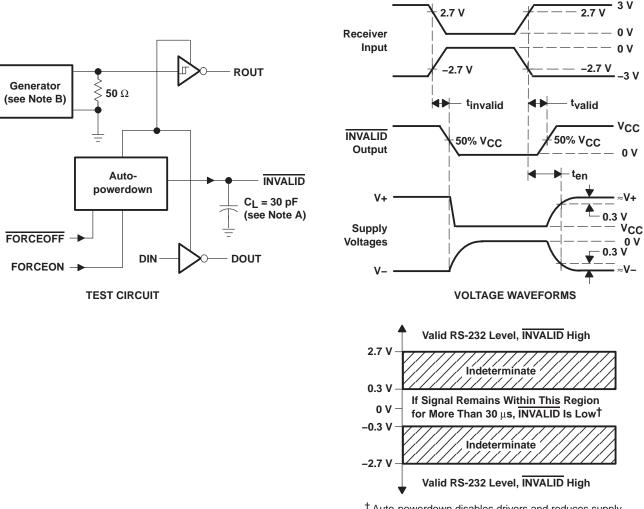
NOTES: A. CL includes probe and jig capacitance.

B. The pulse generator has the following characteristics:  $Z_{O} = 50 \Omega$ , 50% duty cycle,  $t_{f} \le 10$  ns.  $t_{f} \le 10$  ns.

Figure 4. Receiver Enable and Disable Times



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### PARAMETER MEASUREMENT INFORMATION

 $^\dagger$  Auto-powerdown disables drivers and reduces supply current to 1  $\mu A.$ 

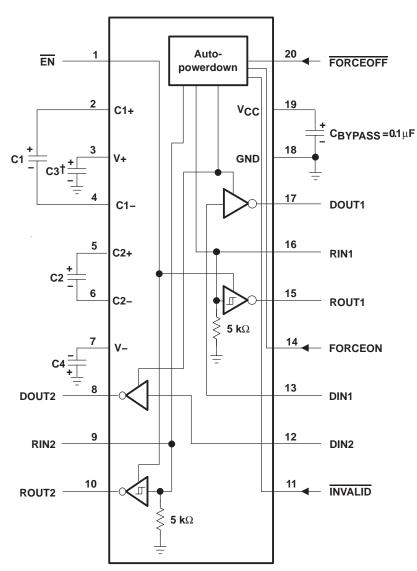
NOTES: A. CL includes probe and jig capacitance.

B. The pulse generator has the following characteristics: PRR = 5 kbit/s,  $Z_0 = 50 \Omega$ , 50% duty cycle,  $t_f \le 10$  ns.  $t_f \le 10$  ns.

### Figure 5. INVALID Propagation Delay Times and Supply Enabling Time



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**APPLICATION INFORMATION** 

 $^{\dagger}$  C3 can be connected to V\_CC or GND. NOTE A: Resistor values shown are nominal.

V <sub>CC</sub> vs CAPACITOR VALUES								
Vcc	C1	C2, C3, C4						
3.3 V ± 0.3 V 5 V ± 0.5 V	0.1 μF 0.047 μF	0.1 μF 0.33 μF						
3 V to 5.5 V	<b>0.1</b> μ <b>F</b>	<b>0.47</b> μF						

Figure 6. Typical Operating Circuit and Capacitor Values



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### PACKAGING INFORMATION

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
SN65C3223DBR	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65C3223DBRE4	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65C3223DBRG4	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65C3223DW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65C3223DWE4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65C3223DWG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65C3223DWR	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65C3223DWRE4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65C3223DWRG4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65C3223PW	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65C3223PWE4	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65C3223PWG4	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65C3223PWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65C3223PWRE4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN65C3223PWRG4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75C3223DBR	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75C3223DBRE4	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75C3223DBRG4	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75C3223DW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75C3223DWE4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75C3223DWG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75C3223DWR	ACTIVE	SOIC	DW	20	2000		CU NIPDAU	Level-1-260C-UNLIM
SN75C3223DWRE4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75C3223DWRG4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75C3223PW	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
SN75C3223PWE4	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75C3223PWG4	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75C3223PWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75C3223PWRE4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75C3223PWRG4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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### TAPE AND REEL INFORMATION





## QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN65C3223DBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
SN65C3223DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.0	2.7	12.0	24.0	Q1
SN65C3223PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
SN75C3223DBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
SN75C3223DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.0	2.7	12.0	24.0	Q1
SN75C3223PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1



# PACKAGE MATERIALS INFORMATION

11-Mar-2008



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN65C3223DBR	SSOP	DB	20	2000	346.0	346.0	33.0
SN65C3223DWR	SOIC	DW	20	2000	346.0	346.0	41.0
SN65C3223PWR	TSSOP	PW	20	2000	346.0	346.0	33.0
SN75C3223DBR	SSOP	DB	20	2000	346.0	346.0	33.0
SN75C3223DWR	SOIC	DW	20	2000	346.0	346.0	41.0
SN75C3223PWR	TSSOP	PW	20	2000	346.0	346.0	33.0

# **MECHANICAL DATA**

MSSO002E - JANUARY 1995 - REVISED DECEMBER 2001

## DB (R-PDSO-G\*\*)

PLASTIC SMALL-OUTLINE

28 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
- D. Falls within JEDEC MO-150



## **MECHANICAL DATA**

MTSS001C - JANUARY 1995 - REVISED FEBRUARY 1999

# PW (R-PDSO-G\*\*)

#### PLASTIC SMALL-OUTLINE PACKAGE

14 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
- D. Falls within JEDEC MO-153



DW (R-PDSO-G20)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).

D. Falls within JEDEC MS-013 variation AC.



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